

# **PHPT60406PY**

# 40 V, 6 A PNP high power bipolar transistor

8 December 2014

**Product data sheet** 

## 1. General description

PNP high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

NPN complement: PHPT60406NY.

### 2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation
- AEC-Q101 qualified

# 3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Motor drive
- Relay replacement

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-40	V
I <sub>C</sub>	collector current		-	-	-6	Α
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; pulsed	-	-	-12	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = -6 A; $I_{B}$ = -600 mA; pulsed; $t_{p} \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	58	78	mΩ



# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter	mb	C
2	Е	emitter		в—
3	Е	emitter	[qj	1.4
4	В	base	وققق	sym132
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

# 6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PHPT60406PY	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669		

# 7. Marking

Table 4. Marking codes

Type number	Marking code
PHPT60406PY	0406PAB

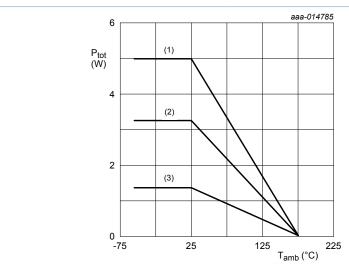
# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-40	V
$V_{CEO}$	collector-emitter voltage	open base		-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-8	V
I <sub>C</sub>	collector current			-	-6	Α
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; pulsed		-	-12	Α
I <sub>B</sub>	base current			-	-800	mA
I <sub>BM</sub>	peak base current	t <sub>p</sub> ≤ 1 ms; pulsed		-	-1.2	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	1.35	W
			[2]	-	3.25	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm<sup>2</sup>.
- [3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [4] Power dissipation from junction to mounting base.



- (1) Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint
- (2) FR4 PCB, mounting pad for collector 6 cm<sup>2</sup>
- (3) FR4 PCB, standard footprint

#### Fig. 1. Power derating curves

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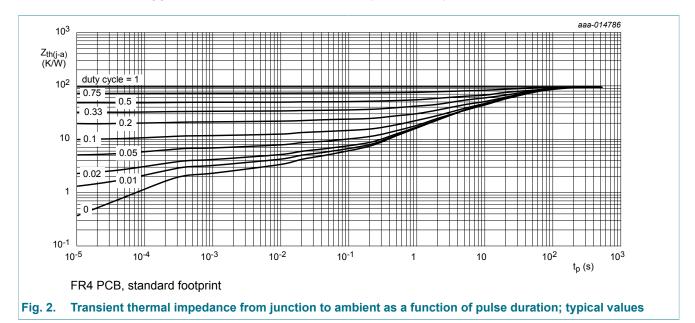
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### 9. Thermal characteristics

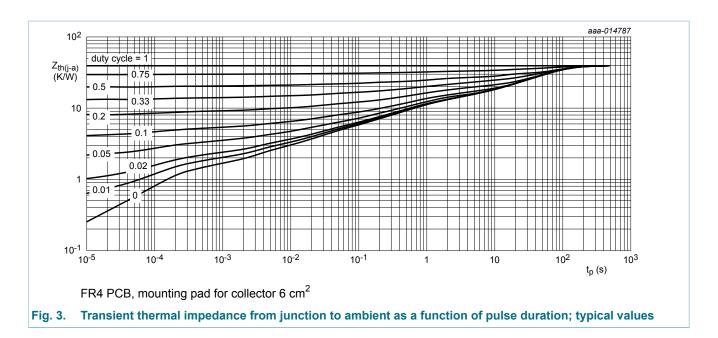
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> the	thermal resistance	in free air	[1]	-	-	111	K/W
	from junction to ambient		[2]	-	-	46	K/W
ambient	ambient		[3]	-	-	30	K/W
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base			-	-	6	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm<sup>2</sup>.
- [3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



**Product data sheet** 



## 10. Characteristics

Table 7. Characteristics

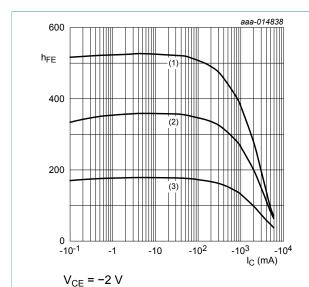
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -32 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	$V_{CB} = -32 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ °C}$	-	-	-50	μΑ
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -32 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = -8 V; $I_{C}$ = 0 A; $T_{amb}$ = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -2 V; $I_{C}$ = -500 mA; $T_{amb}$ = 25 °C	210	300	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -1 A; $t_{p} \le 300 \text{ µs}$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C; pulsed	190	260	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -3 A; $t_{p} \le 300 \text{ µs}$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C; pulsed	110	150	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -6 A; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	50	90	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = -1 A; $I_{B}$ = -50 mA; $t_{p}$ ≤ 300 µs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	_	-60	-100	mV
		$I_C$ = -3 A; $I_B$ = -300 mA; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C; pulsed	-	-140	-210	mV
		$I_C$ = -6 A; $I_B$ = -300 mA; pulsed; $t_p \le 300$ μs; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	-	-350	-540	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -6 A; $I_B$ = -600 mA; pulsed; $t_p \le 300$ μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	58	78	mΩ

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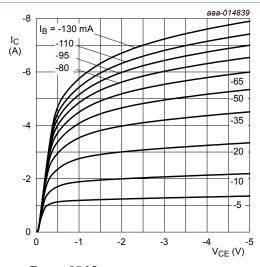
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
DESat	base-emitter saturation voltage	$I_{C}$ = -1 A; $I_{B}$ = -50 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	-	-0.85	-0.95	V
		$I_{C}$ = -3 A; $I_{B}$ = -300 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	-	-1	-1.1	V
		$I_C$ = -6 A; $I_B$ = -300 mA; pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}C$	-	-1.05	-1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE}$ = -2 V; $I_{C}$ = -0.5 A; $T_{amb}$ = 25 °C	-	-0.7	-0.8	V
t <sub>d</sub>	delay time	$V_{CC}$ = -12.5 V; $I_{C}$ = -3 A; $I_{Bon}$ = -150 mA; $I_{Boff}$ = 150 mA;	-	15	-	ns
t <sub>r</sub>	rise time		-	90	-	ns
t <sub>on</sub>	turn-on time	T <sub>amb</sub> = 25 °C	-	105	-	ns
ts	storage time		-	205	-	ns
t <sub>f</sub>	fall time		-	65	-	ns
t <sub>off</sub>	turn-off time		-	270	-	ns
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -500 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	-	110	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	59	-	pF



(1)  $T_{amb}$  = 100 °C

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig. 4. DC current gain as a function of collector current; typical values



 $T_{amb}$  = 25 °C

Fig. 5. Collector current as a function of collectoremitter voltage; typical values

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<sup>(2)</sup>  $T_{amb}$  = 25 °C

-1.2 V<sub>BEsat</sub>

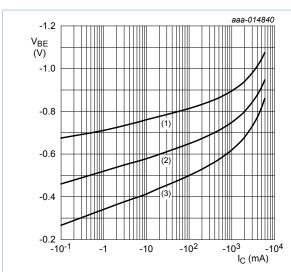
-1.0

-0.8

-0.6

(V)

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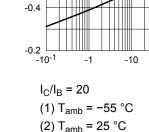


$$V_{CE} = -2 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = 100 °C



(3)  $T_{amb}$  = 100 °C

Fig. 6. Base-emitter voltage as a function of collector current; typical values

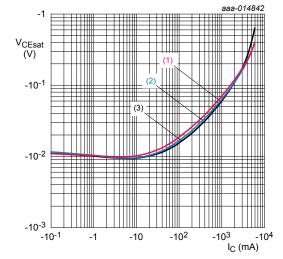


(3)

 $-10^{2}$ 

-10<sup>4</sup>

 $I_C$  (mA)



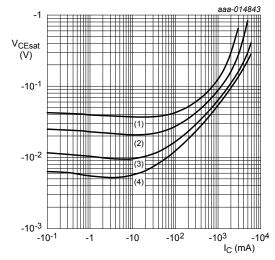
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

$$(3) T_{amb} = -55 °C$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

(1)  $I_C/I_B = 100$ 

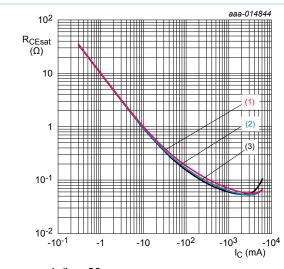
(2)  $I_C/I_B = 50$ 

(3)  $I_C/I_B = 20$ 

 $(4) I_C/I_B = 10$ 

Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

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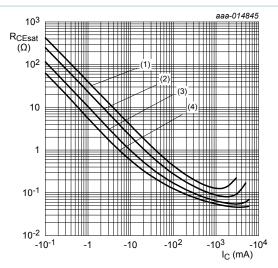
$$I_C/I_B = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

(1) 
$$I_C/I_B = 100$$

(2) 
$$I_C/I_B = 50$$

(3) 
$$I_C/I_B = 20$$

(4) 
$$I_{\rm C}/I_{\rm B} = 10$$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

### 11. Test information

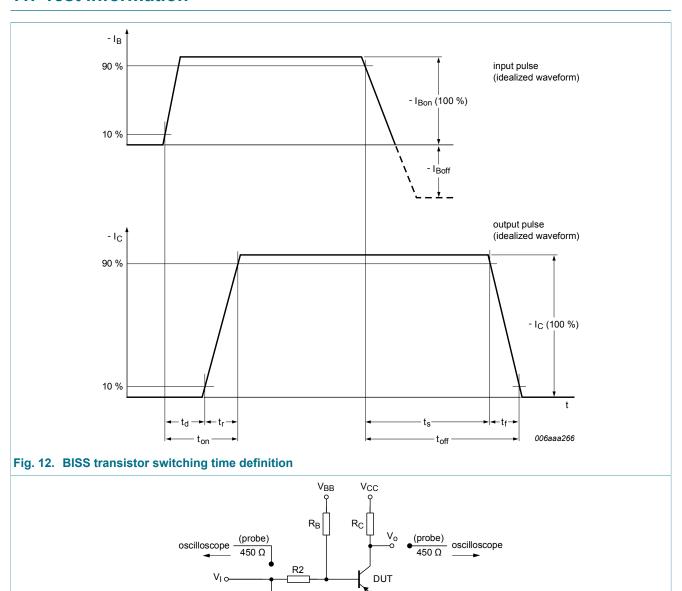


Fig. 13. Test circuit for switching times

### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

mgd624

# 12. Package outline

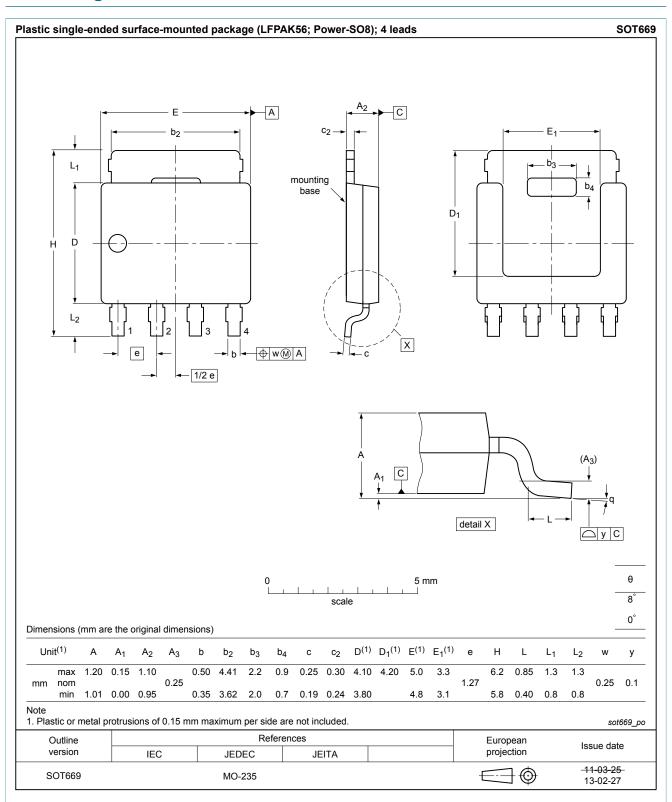
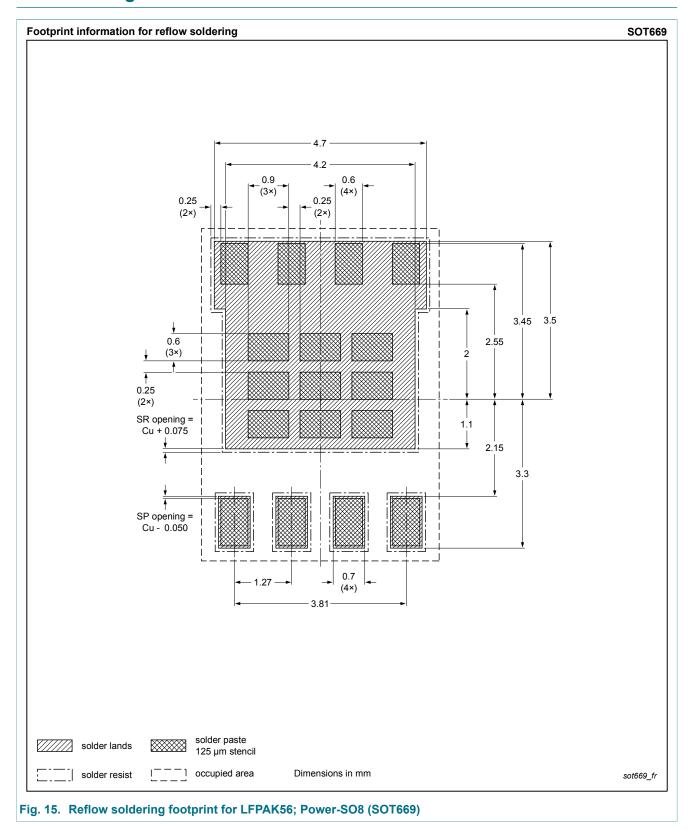


Fig. 14. Package outline LFPAK56; Power-SO8 (SOT669)

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# 13. Soldering



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# 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT60406PY v.1	20141208	Product data sheet	-	-

## 15. Legal information

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Document status [1][2]	Product status [3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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